

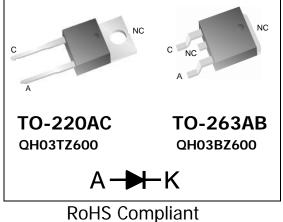
QH03TZ600, QH03BZ600 Qspeed[™] Family

600 V, 3 A H-Series PFC Diode

Product Summary

| I _{F(AVG)} | 3 | А |
|---|------|----|
| V _{RRM} | 600 | V |
| Q _{RR} (Typ at 125 °C) | 14.8 | nC |
| I _{RRM} (Typ at 125 °C) | 1.35 | A |
| Softness t _B /t _A (Typ at 125 °C) | 1.1 | |

Pin Assignment



Package uses Lead-free plating and Green mold compound. Halogen free per IEC 61249-2-21.

Absolute Maximum Ratings

General Description

This device has the lowest Q_{RR} of any 600 V silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- Power Factor Correction (PFC) boost diode
- Motor drive circuits
- DC-AC Inverters

Features

- Low Q_{RR} , low I_{RRM} , low t_{RR}
- High dI_F/dt capable (1000 A / μs)
- Soft recovery

Benefits

- Increases efficiency
 - Eliminates need for snubber circuits
 - Reduces EMI filter component size & count
- Enables extremely fast switching

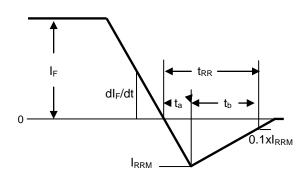
Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

| Symbol | Parameter | Conditions | Rating | Units |
|---------------------|--------------------------------------|--|------------|-------|
| V _{RRM} | Peak repetitive reverse voltage | $T_{J} = 25 \ ^{\circ}C$ | 600 | V |
| I _{F(AVG)} | Average forward current | $T_{J} = 150 \text{ °C}, T_{C} = 120 \text{ °C}$ | 3 | А |
| I _{FSM} | Non-repetitive peak surge current | 60 Hz, $\frac{1}{2}$ cycle, $T_c = 25 \text{ °C}$ | 35 | А |
| I _{FSM} | Non-repetitive peak surge current | V_2 cycle of t = 28 μ s Sinusoid, T _C = 25 °C | 350 | А |
| ΤJ | Operating junction temperature range | | -55 to 150 | °C |
| T _{STG} | Storage temperature | | -55 to 150 | °C |
| | Lead soldering temperature | Leads at 1.6 mm from case, 10 sec | 300 | °C |
| VISOL | Isolation voltage (leads-to-tab) | AC, TO-220 | 2500 | V |
| VISOL | Isolation voltage (leads-to-tab) | AC, TO-263 | 1500 | V |
| P _D | Power dissipation | $T_{C} = 25 \ ^{\circ}C$ | 30.4 | W |

| Symbol | Resistance from: | Conditions | | | Rating | | Units | |
|--|---|--|------------------------|------|----------|------|--------|------|
| R _{θJA} | Junction to ambient | TO-220 (only) | | | | 62 | °C/W | |
| $R_{	ext{	ext{	ext{	ext{	ext{	ext{	ext{	ext$ | Junction to case | | | | | | 4.1 | °C/W |
| Electric | cal Specificatior | ns at $T_J = 25$ °C | C (unless | othe | rwis | se s | specif | ïed) |
| Symbol | Parameter | Conditions Min Typ Max | | | | | Units | |
| DC Chara | acteristics | • | | | <u>.</u> | | | |
| | Deveree everent | $V_{R} = 600 V$, $T_{J} = 25 °$ | 0 | - | - | | 250 | μA |
| I _R | Reverse current | $V_{R} = 600 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$ | | - 0. | | 2 | - | mA |
| VF | Forward voltage | $I_F = 3 \text{ A}, T_J = 25 \text{ °C}$ | | - | 2.5 | 2 | 3.0 | V |
| VF | Forward voltage | $I_F = 3 \text{ A}, T_J = 150 ^{\circ}\text{C}$ | | - | 2.1 | 1 | - | V |
| CJ | Junction capacitance | $V_{R} = 10 V$, 1 MHz | | - | 11 | | - | рF |
| Dynamic Characteristics | | | | | | | | |
| | Reverse recovery time | $ dI/dt = 200 \ \text{A}/\mu \text{s} \\ V_R = 400 \ \text{V}, \ I_F = 3 \ \text{A} $ | $T_J = 25 \ ^{\circ}C$ | - | 9.8 | 3 | - | ns |
| t _{RR} | Reverse recovery time | | $T_J = 125 \ ^\circ C$ | - | 16. | 1 | - | ns |
| 0 | Reverse recovery | $dI/dt = 200 A/\mu s$ | $T_J = 25 \ ^\circ C$ | - | 5.8 | 3 | 10 | nC |
| Q _{RR} | charge | $V_{R} = 400 V$, $I_{F} = 3 A$ | $T_J = 125 \ ^\circ C$ | - | 14. | 8 | - | nC |
| | Maximum reverse | $dI/dt = 200 A/\mu s$ | $T_J = 25 \ ^\circ C$ | - | 0.9 | 3 | 1.4 | А |
| RRM | recovery current $V_R = 400 V$, $I_F = 3 A$ | $V_{R} = 400 V, I_{F} = 3 A$ | $T_J = 125 \ ^\circ C$ | - | 1.3 | 5 | - | А |
| <u> </u> | S Softness factor = $\frac{t_B}{t_A}$ $\frac{dI/dt}{V_R} = 200 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}, I_F = 3 \text{ A}$ | $dI/dt = 200 A/\mu s$ | $T_J = 25 \ ^\circ C$ | - | 0.9 | 2 | - | |
| S | | T _J = 125 °C | - | 1.1 | 1 | - | | |

Thermal Resistance

Note to component engineers: H-Series diodes employ Schottky technologies in their design and construction. Therefore, Component Engineers should plan their test setups to be similar to those for traditional Schottky test setups. (For additional details, see Application Note AN-300.)



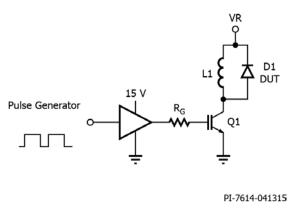
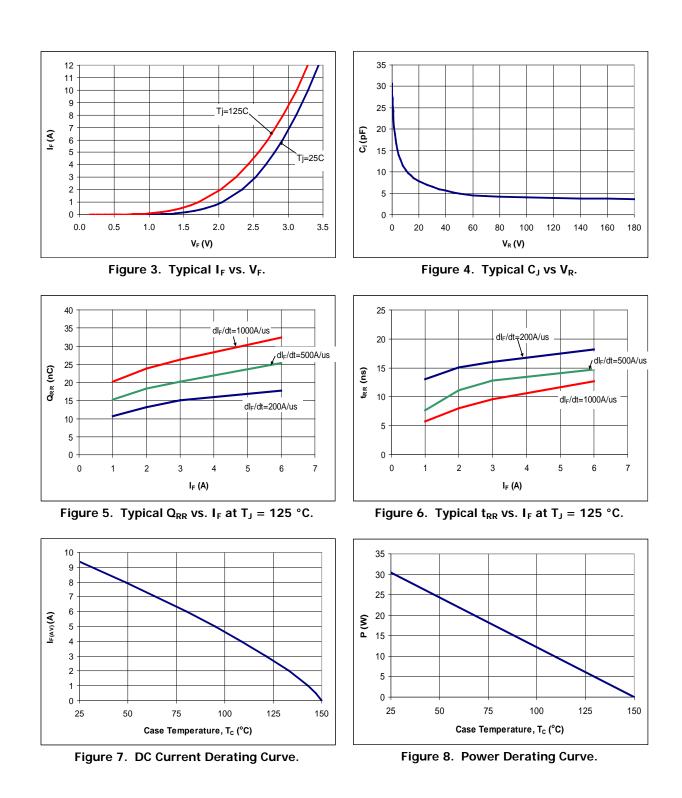


Figure 1. Reverse Recovery Definitions.









Electrical Specifications at $T_J = 25$ °C (unless otherwise specified)

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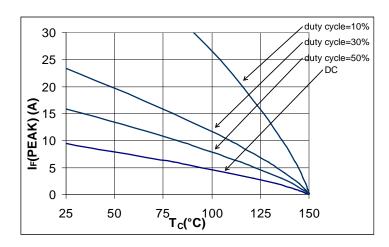


Figure 9. I_F (PEAK) vs. $T_{C_1} f = 70 \text{ kHz}$.

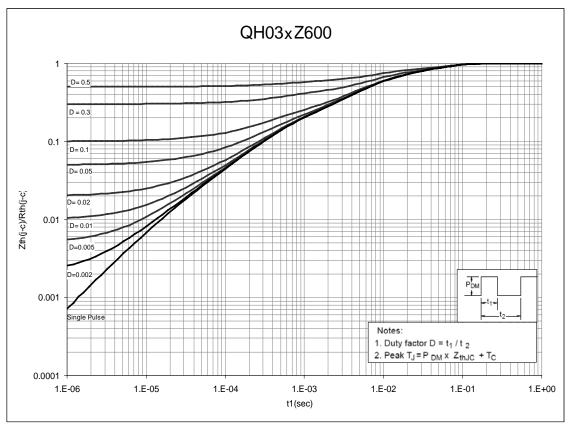


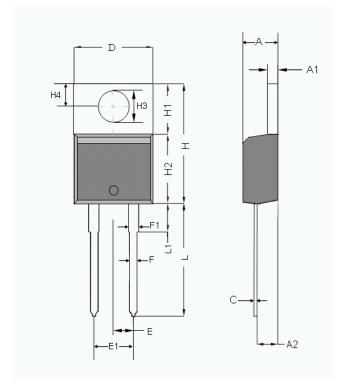
Figure 10. Normalized Maximum Transient Thermal Impedance.





Dimensional Outline Drawing

TO-220AC



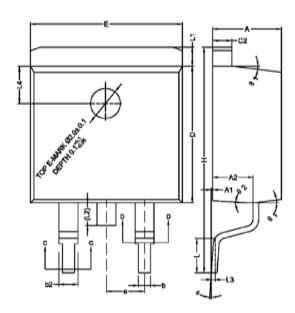
| | Millimeters | | | |
|-----|-------------|-------|--|--|
| Dim | MIN | MAX | | |
| Α | 4.32 | 4.70 | | |
| A1 | 1.14 | 1.40 | | |
| A2 | 2.03 | 2.79 | | |
| С | 0.34 | 0.610 | | |
| D | 9.65 | 10.67 | | |
| E | 2.49 | 2.59 | | |
| E1 | 4.98 | 5.18 | | |
| F | 0.508 | 1.016 | | |
| F1 | 1.14 | 1.78 | | |
| н | 14.71 | 16.51 | | |
| H1 | 5.84 | 6.795 | | |
| H2 | 8.40 | 9.00 | | |
| H3 | 3.53 | 3.96 | | |
| H4 | 2.54 | 3.05 | | |
| L | 12.70 | 14.22 | | |
| L1 | - | 6.35 | | |





Dimensional Outline Drawing

TO-263AB

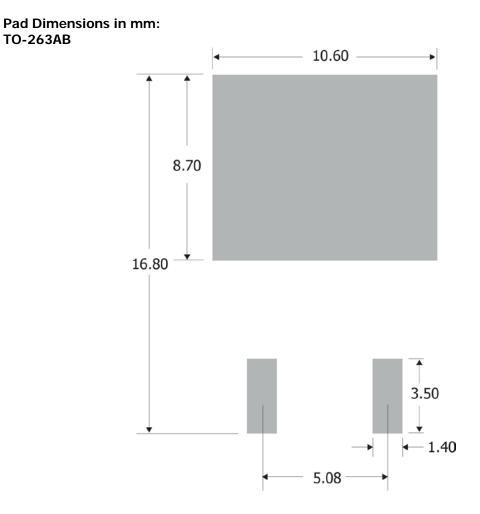


| | Millimeters | | | |
|-----|-------------|----------|--|--|
| Dim | MIN | MAX | | |
| А | 4.40 | 4.70 | | |
| A1 | 0.00 | 0.25 | | |
| A2 | 2.59 | 2.79 | | |
| b | 0.77 | 0.90 | | |
| b2 | 1.23 | 1.36 | | |
| c2 | 1.22 | 1.32 | | |
| D | 9.05 | 9.25 | | |
| E | 10.06 | 10.26 | | |
| е | 2.54 BSC | 2.54 BSC | | |
| Н | 14.70 | 15.50 | | |
| L | 2.00 | 2.60 | | |
| L1 | 1.17 | 1.40 | | |
| L2 | - | 1.75 | | |
| L3 | 0.25 BSC | 0.25 BSC | | |
| L4 | 2.00 BSC | 2.00 BSC | | |
| Θ | 0° | 8° | | |
| 01 | 5° | 9° | | |
| 02 | 1° | 5° | | |

| Mechanical Mounting Method | d Maximum Torque / Pressure specification | | |
|-----------------------------------|---|--|--|
| Screw through hole in package tab | 1 Newton Meter (nm) or 8.8 inch-pounds (lb-in) | | |
| Clamp against package body | 12.3 kilogram-force per square centimeter (kgf/cm ²) or 175 lbf/in ² | | |







Footprint and Solder Pad Dimensions

Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

| Part Number | Package | Packing |
|-------------|----------|----------------|
| QH03TZ600 | TO-220AB | 50 units/tube |
| QH03BZ600 | TO-263AB | 800 units/reel |

The information contained in this document is subject to change without notice.



QH03TZ600, QH03BZ600

| Revision | Notes | Date |
|----------|--|-------|
| 1.0 | Released by Qspeed | 01/10 |
| 1.1 | Converted to Power Integrations Document | 01/11 |
| 1.2 | Added QH03BZ600 | 02/13 |
| 1.3 | Updated with new Brand Style. Added footprint and solder pad dimension for TO-263AB package. | 11/15 |





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